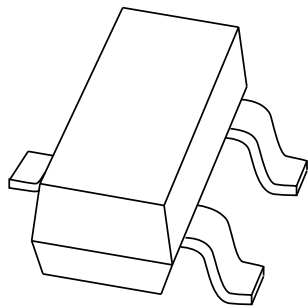


DATA SHEET



PMBTA55; PMBTA56 PNP general purpose transistors

Product specification
Supersedes data of September 1994
File under Discrete Semiconductors, SC04

1997 Apr 22

PNP general purpose transistors

PMBTA55; PMBTA56

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 80 V).

APPLICATIONS

- General purpose switching and amplification, e.g. telephony and professional communication equipment.

DESCRIPTION

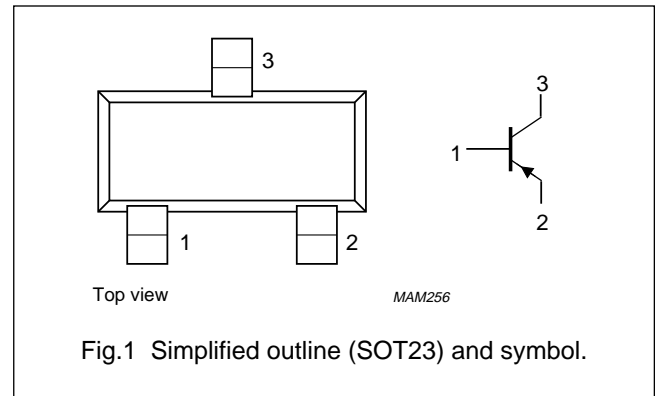
PNP transistor in a SOT23 plastic package.
NPN complement: PMBTA06.

MARKING

TYPE NUMBER	MARKING CODE
PMBTA55	p2H
PMBTA56	p2G

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	PMBTA55		–	–60	V
	PMBTA56		–	–80	V
V _{CEO}	collector-emitter voltage	open base			
	PMBTA55		–	–60	V
	PMBTA56		–	–80	V
I _{CM}	peak collector current		–	–1	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	–	250	mW
h _{FE}	DC current gain	I _C = –100 mA; V _{CE} = –1 V	100	–	
f _T	transition frequency	I _C = –100 mA; V _{CE} = –1 V; f = 100 MHz	50	–	MHz

PNP general purpose transistors

PMBTA55; PMBTA56

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	PMBTA55		–	–60	V
	PMBTA56		–	–80	V
V _{CEO}	collector-emitter voltage	open base			
	PMBTA55		–	–60	V
	PMBTA56		–	–80	V
V _{EBO}	emitter-base voltage	open collector	–	–5	V
I _C	collector current (DC)		–	–500	mA
I _{CM}	peak collector current		–	–1	A
I _{BM}	peak base current		–	–200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	–	250	mW
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current				
	PMBTA55	I _E = 0; V _{CB} = –60 V	–	–50	nA
	PMBTA56	I _E = 0; V _{CB} = –80 V	–	–50	nA
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = –5 V	–	–50	nA
h _{FE}	DC current gain	I _C = –10 mA; V _{CE} = –1 V	100	–	
		I _C = –100 mA; V _{CE} = –1 V	100	–	
V _{CEsat}	collector-emitter saturation voltage	I _C = –100 mA; I _B = –10 mA	–	–250	mV
V _{BE}	base-emitter voltage	I _C = –100 mA; V _{CE} = –1 V	–	–1.2	V
f _T	transition frequency	I _C = –100 mA; V _{CE} = –1 V; f = 100 MHz	50	–	MHz

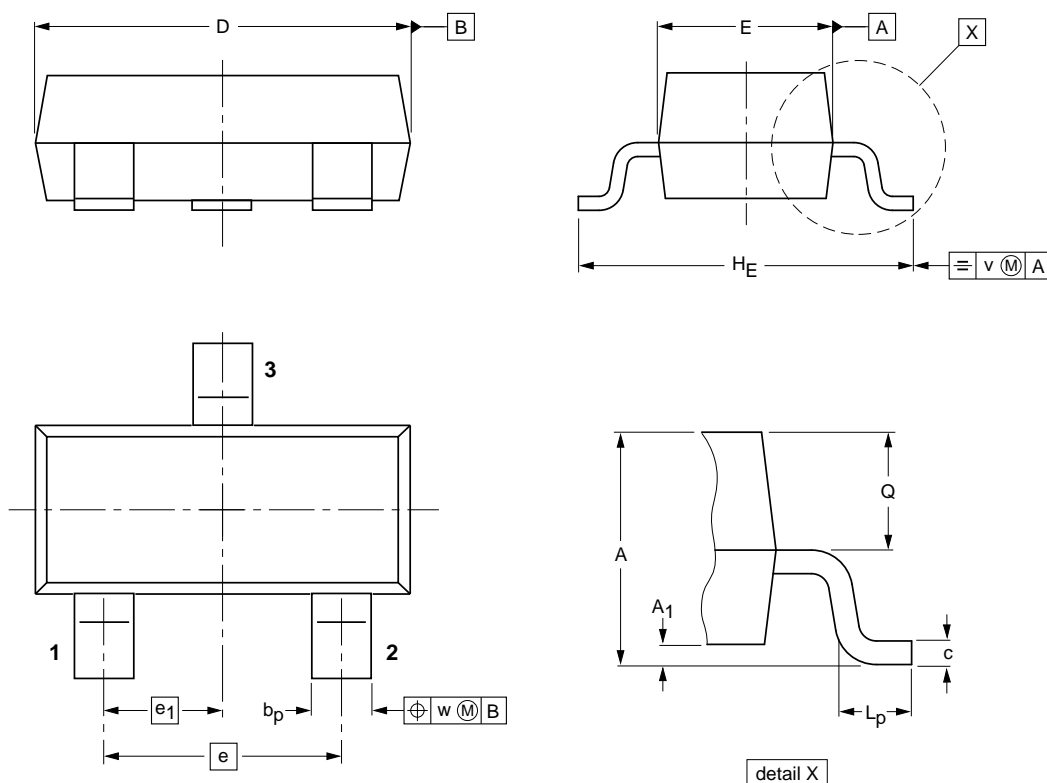
PNP general purpose transistors

PMBTA55; PMBTA56

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT23						97-02-28

PNP general purpose transistors

PMBTA55; PMBTA56

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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PNP general purpose transistors

PMBTA55; PMBTA56

NOTES

PNP general purpose transistors

PMBTA55; PMBTA56

NOTES

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